NSN 5962-01-101-3754



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-01-101-3754 **Body Length:** 0.840 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.140 inches and 0.180 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** +0.0/+70.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and positive outputs and w/buffered output and w/enable **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 11 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 20.0 volts power source **Time Rating Per Chacteristic:** 300.00 nanoseconds propagation delay time, low to high level output and 300.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:** 15280-48-055847 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a **Unit Of Measure:**

Yes - demil/mli

Demilitarization:

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